



# Advanced CMOS Logic – 54AC273

8-bit D-Type Flip-Flop with common reset and clock inputs in bare die form

Rev 1.0  
07/12/2021

## Description

The 54AC273 consists of eight D-type flip-flops fabricated using a 1.5 $\mu$ m 5V CMOS process combining high speed performance LSTTL performance with CMOS low power consumption. Each flip-flop is equipped with buffered common Clock (CP) and common Reset ( $\overline{MR}$ ) inputs. A low-to-high clock transition loads each flip-flop. Reset is asynchronous and enabled with active low. Inputs accept standard CMOS outputs or LSTTL outputs using pull-up resistors. Inputs are also equipped with protection circuits against static discharge and transient excess voltage.

## Features:

- Buffered common clock
- Buffered asynchronous master reset
- Outputs Source/Sink 24mA
- Low input current: 1 $\mu$ A
- Outputs directly interface CMOS, NMOS and TTL
- Operating voltage range: 2.0V to 6.0V
- Function compatible with 54HC273
- Full military temperature range.

## Ordering Information

The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection
- "H" - MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" - MIL-STD-883 /2010A Visual Inspection (Space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

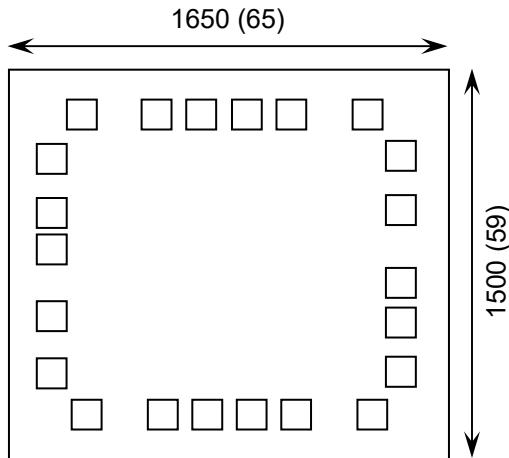
For further information on LAT process flows see below.

[www.siliconsupplies.com/quality/bare-die-lot-qualification](http://www.siliconsupplies.com/quality/bare-die-lot-qualification)

## Supply Formats:

- Default – Die in Waffle Pack (100 per tray capacity)
- \* Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <> 460 $\mu$ m(18 Mils) – On request
- Assembled into Ceramic Package – On request

## Die Dimensions in $\mu$ m (mils)



## Mechanical Specification

Die Size (Unsawn)	1650 x 1500 65 x 59	$\mu$ m mils
Minimum Bond Pad Size	108 x 108 4.25 x 4.25	$\mu$ m mils
Die Thickness	460 ( $\pm 20$ ) 18.11 ( $\pm 0.79$ )	$\mu$ m mils
Top Metal Composition	Al 1%Si 1.1 $\mu$ m	
Back Metal Composition	N/A – Bare Si	

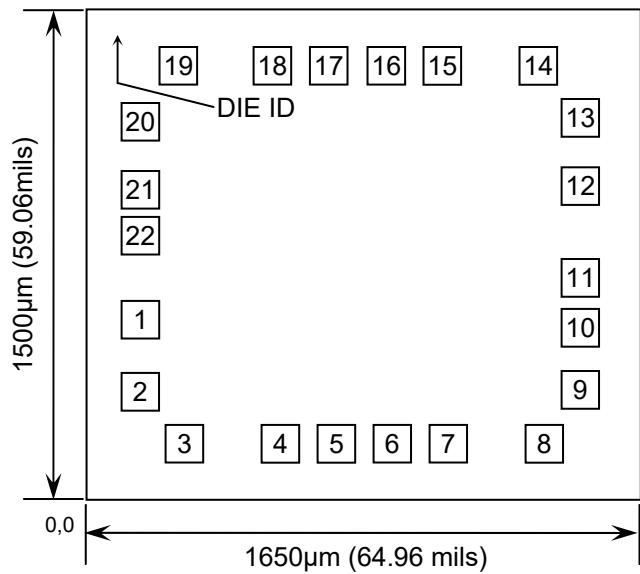




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## Pad Layout and Functions

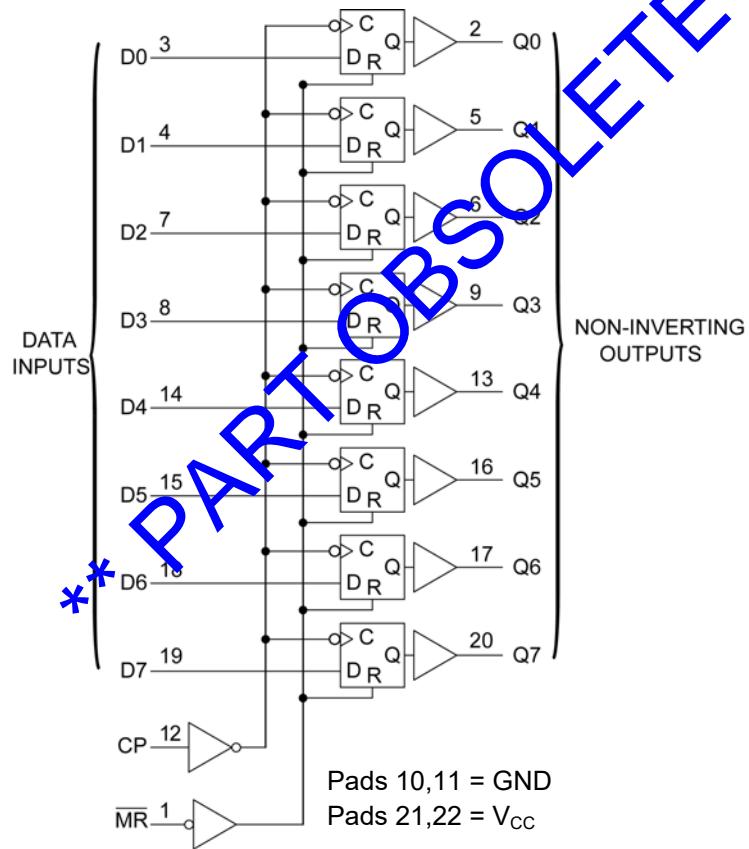
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PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	MR	0.120	0.507
2	Q0	0.117	0.286
3	D0	0.247	0.127
4	D1	0.531	0.127
5	Q	0.699	0.127
6	Q2	0.867	0.127
7	D2	1.035	0.127
8	D3	1.318	0.127
9	Q3	1.426	0.294
10	GND	1.426	0.483
11	GND	1.426	0.570
12	CP	1.428	0.900
13	Q4	1.426	1.120
14	D4	1.299	1.279
15	D5	1.015	1.279
16	Q5	0.847	1.279
17	Q6	0.679	1.279
18	D6	0.511	1.279
19	D7	0.228	1.279
20	Q7	0.117	1.111
21	V <sub>CC</sub>	0.117	0.903
22	V <sub>CC</sub>	0.117	0.816

CONNECT CHIP BACK TO V<sub>CC</sub>

## Logic Diagram



## Truth Table

INPUTS		OUTPUT	
MR	CP	D	Q
L	X	X	L
H	/	H	H
H	/	L	L
H	L	X	No Change
H	/	X	No Change

H = High level (steady state)  
L = Low level (steady state)  
X = Don't care





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	V <sub>CC</sub>	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> +0.5	V
DC Output Voltage (Referenced to GND)	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> +0.5	V
DC Input Current, per pad	I <sub>IN</sub>	±20	mA
DC Output Current, per pad	I <sub>OUT</sub>	±50	mA
DC Supply Current, V <sub>CC</sub> or GND	I <sub>CC</sub>	±50	mA
Power Dissipation in Still Air <sup>2</sup>	P <sub>D</sub>	750	mW
Storage Temperature Range	T <sub>STG</sub>	-65 to 150	°C

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on die attach and assembly method.

## Recommended Operating Conditions<sup>3</sup> (Voltages referenced to GND)

PARAMETER	SYMBOL	MIN	MAX	UNITS
DC Supply Voltage	V <sub>CC</sub>	2.0	6.0	V
DC Input or Output Voltage	V <sub>IN</sub> , V <sub>OUT</sub>	0	V <sub>CC</sub>	V
Operating Temperature Range	T <sub>J</sub>	-55	+125	°C
Output current - High	I <sub>OH</sub>	-	-24	mA
Output current - Low	I <sub>OL</sub>	-	24	mA
Input Rise or Fall rate (V <sub>IN</sub> from 30% to 70% V <sub>CC</sub> )	V <sub>CC</sub> = 3.0V V <sub>CC</sub> = 4.5V V <sub>CC</sub> = 5.5V	0 0 0	150 40 25	ns/V

3. This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>IN</sub> and V<sub>OUT</sub> should be constrained to the range GND ≤ (V<sub>IN</sub> or V<sub>OUT</sub>) ≤ V<sub>CC</sub>. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

## DC Electrical Characteristics (Voltages referenced to GND)

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum High-Level Input Voltage	V <sub>IH</sub>	3.0V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> -0.1V	2.1	2.1	2.1	V
		4.5V		3.15	3.15	3.15	
		5.5V		3.85	3.85	3.85	
Maximum Low-Level Input Voltage	V <sub>IL</sub>	3.0V	V <sub>OUT</sub> = 0.1V or V <sub>CC</sub> -0.1V	0.9	0.9	0.9	V
		4.5V		1.35	1.35	1.35	
		5.5V		1.65	1.65	1.65	

4. -55°C ≤ T<sub>J</sub> ≤ +125°C





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## DC Electrical Characteristics Continued (Voltages Referenced to GND)

PARAMETER	SYMBOL	V <sub>CC</sub>	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum High-Level Output Voltage	V <sub>OH</sub>	3.0V	I <sub>OUT</sub> ≤ -50µA	2.9	2.9	2.9	V
		4.5V		4.4	4.4	4.4	
		5.5V		5.4	5.4	5.4	
		3.0V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> = -12 mA	2.56	2.46	2.40	
		4.5V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> = -24mA <sup>5</sup>	3.86	3.76	3.70	
		5.5V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> = -24mA <sup>5</sup>	4.86	4.76	4.70	
		5.5V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> I <sub>OH</sub> = -50mA <sup>6</sup>	-	-	3.85	
		3.0V	I <sub>OUT</sub> = 50µA	0.1	0.1	0.1	
Maximum Low-Level Output Voltage	V <sub>OL</sub>	4.5V		0.1	0.1	0.1	
		5.5V		0.1	0.1	0.1	
		3.0V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 12mA*	0.36	0.44	0.5	V
		4.5V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 24mA <sup>5</sup>	0.36	0.44	0.5	
		5.5V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   ≤ 24mA <sup>5</sup>	0.36	0.44	0.5	
		5.5V	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>OUT</sub>   50mA <sup>6</sup>	-	-	1.65	
		3.5V	V <sub>IN</sub> = V <sub>CC</sub> or GND	±0.1	±1.0	±1.0	µA
Maximum Input Leakage Current	I <sub>IN</sub>	3.5V		-	-	-	µA
Minimum Dynamic Output Current <sup>7</sup>	I <sub>OD</sub>	5.5V	V <sub>OLD</sub> = 1.65V Max	-	75	50	mA
	I <sub>OHD</sub>	5.5V	V <sub>OHD</sub> = 3.85V Min	-	-75	-50	
Maximum Quiescent Supply Current	I <sub>CC</sub>	5.5V	V <sub>IN</sub> = V <sub>CC</sub> or GND I <sub>OUT</sub> = 0µA	8	80	160	µA

5. All outputs loaded; thresholds on input associated with output under test. 6. Test time 1sec max, measurement made by forcing indicated current and measuring voltage to minimize power dissipation. Test verifies a minimum 75Ω transmission-line drive capability at 125°C 7. Maximum test duration 2ms, one output loaded at a time

\*\* PART OBSOLETE \*\*





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## AC Electrical Characteristics<sup>8</sup> ( $V_{CC}$ 3.3V ±0.3V, $V_{CC}$ 5V ±0.3V)

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PARAMETER	SYMBOL	$V_{CC}$	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum Clock Frequency (Figure 1)	$f_{max}$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	90	75	75	MHz
		5.0V		140	125	90	
Maximum Propagation Delay CP to Q (Figure 1)	$t_{PLH}$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	12.5	14.0	15.0	ns
		5.0V		9.0	10.0	11.0	
	$t_{PHL}$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	13.0	14.5	16.0	ns
		5.0V		10.0	11.0	11.5	
Maximum Propagation Delay MR to Q (Figure 2)	$t_{PLH}$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	13.0	14.0	16.5	ns
		5.0V		10.0	10.5	12.0	
	$t_{PHL}$	3.3V		12.0	14.0	16.0	ns
		5.0V		8.5	10.0	11.5	
Maximum Input Capacitance	$C_{IN}$	-	-	4.5	4.5	4.5	pF
Power Dissipation Capacitance <sup>9</sup>	$C_{PD}$	-	$T_J = 25^\circ\text{C}$ , $V_{CC} = 5.0\text{V}$	TYPICAL			
				50			pF

8. Not production tested in die form, characterized by chip design.

9. Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

## Timing Requirements<sup>6</sup> ( $V_{CC}$ 3.3V ±0.3V, $V_{CC}$ 5V ±0.3V)

PARAMETER	SYMBOL	$V_{CC}$	CONDITIONS	LIMITS			UNITS
				25°C	85°C	FULL RANGE <sup>4</sup>	
Minimum Setup Time, D to CP (Figure 3)	$t_{SU}$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	5.5	6.0	8.0	ns
		5V		4.0	4.5	5.0	
Minimum Hold Time, D to CP (Figure 3)	$t_h$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	0	0	0	ns
		5V		1.0	1.0	1.0	
	$t_w$	3.3V		5.5	6.0	6.5	ns
		5V		4.0	4.5	5.0	
*Minimum Pulse Width, CP (Figure 1)	$t_w$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	5.5	6.0	10.0	ns
		5V		4.0	4.5	6.5	
	$t_w$	3.3V		5.5	6.0	6.0	
		5V		4.0	4.5	4.0	
Minimum Recovery Time, MR to CP (Figure 2)	$t_{rec}$	3.3V	$C_L = 50\text{pF}$ , Input $t_r = t_f = 3\text{ns}$	3.5	4.5	6.0	ns
		5V		2.0	3.0	4.0	





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## Switching Waveforms

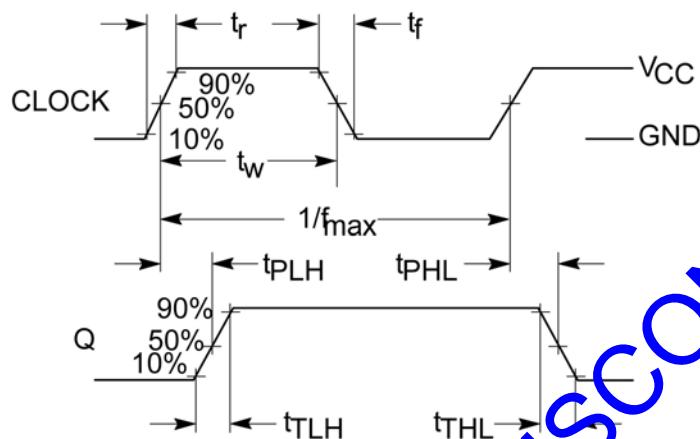


Figure 1 – Propagation Delay & Output Transition Time

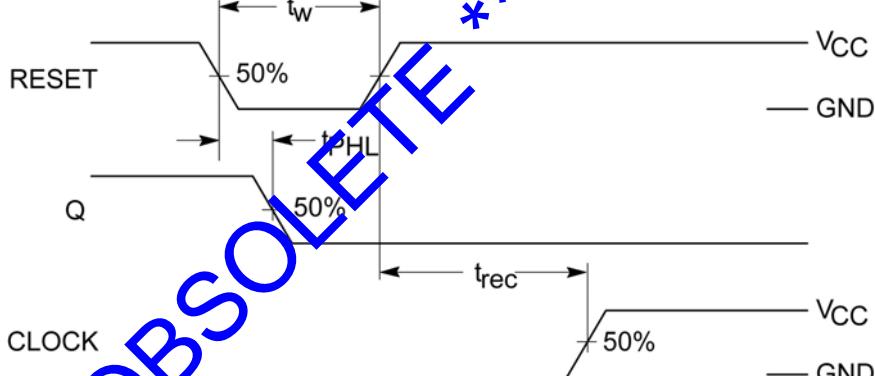


Figure 2 – Propagation Delay – Reset to Q

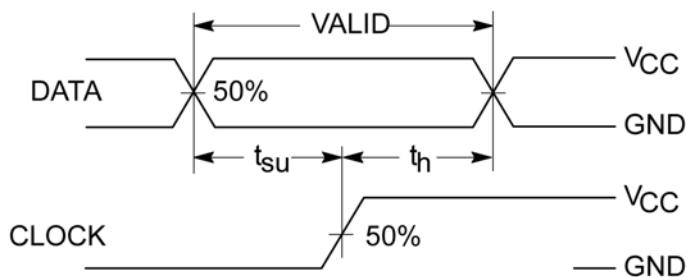


Figure 3 – Timing Requirements

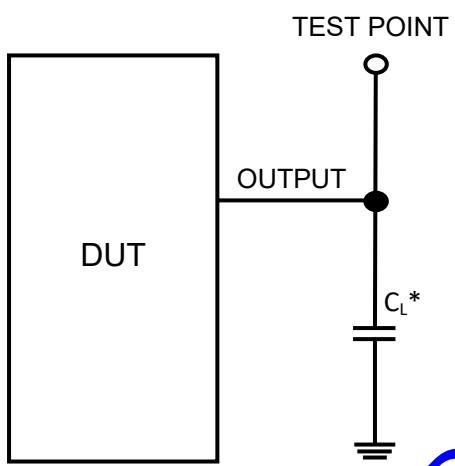


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## Test Circuit



\* Includes all probe and jig capacitance

Figure 4

\*\* PART OBSOLETE - DISCONTINUED

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